

T-4613-29



# 27HC191/27HC291

## 16K (2K x 8) High Speed CMOS UV Erasable PROM

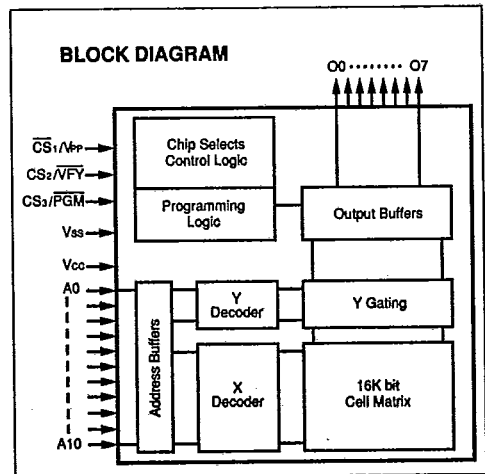
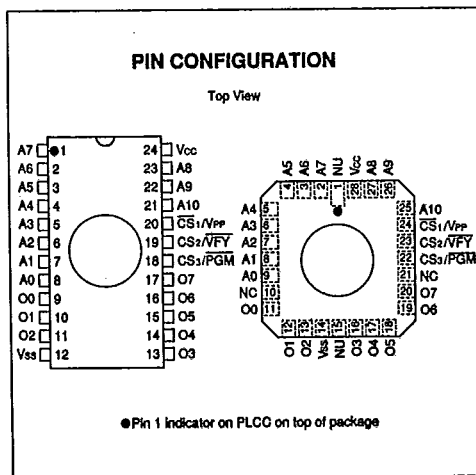
### FEATURES

- Bipolar performance
  - 35ns Access time available
- CMOS technology for low power consumption
  - 65mA Active current
  - 100µA Standby current (low power option)
- OTP (one time programming) available
- Auto-insertion-compatible plastic packages
- Auto ID™ aids automated programming
- Two programming algorithms allow improved programming times
  - Fast programming
  - Express
- Organized in 2K x 8: bipolar PROM pinouts
  - 24-pin Dual-in-line package
  - 28-pin Chip carrier (leadless or plastic)
- Extended temperature ranges available:
  - Commercial: 0° C to 70° C
  - Industrial: -40° C to 85° C
  - Military\*\*: -55° C to 125° C

### DESCRIPTION

The Microchip Technology Inc 27HC191 and 27HC291 are CMOS 16K bit ultraviolet light Erasable (electrically) Programmable Read Only Memory. The devices are organized into 2K words of 8 bits each. Advanced CMOS technology allows bipolar speed with a significant reduction in power. A low power option (L) allows further reduction in the standby power requirement to 100µA. The 27HC191/27HC291 EPROMs are fully tested and then erased before shipment. This ensures the highest possible yield to the customer pattern. The 27HC191/27HC291 are configured in a standard bipolar PROM pinout which allows an easy upgrade for present 16K Bipolar PROM users. The 27HC191 is packaged in a standard 600 mil DIP and the 27HC291 is packaged in a 300 mil DIP. One Time Programming (OTP) is available for low cost (plastic) applications. The 27HC191/27HC291 allow DSP and other high performance microprocessors to run at full speed without the need of wait states. CMOS design and processing make this part suitable for applications where reliability and reduced power consumption are essential.

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\*\*See 27HC191/27HC291 Military Data Sheet DS60008

PIN FUNCTION TABLE	
Name	Function
A0 - A10	Address Inputs
CS1/VPP	Chip Select/Program Voltage
CS2/VFY	Chip Select/Program Verify
CS3/PGM	Chip Select/Program
O0 - O7	Data Output
Vcc	+5V Power Supply
Vss	Ground
NC	No Connection; No Internal Connection
NU	Not Used; No External Connection Is Allowed

**ELECTRICAL CHARACTERISTICS**  
**Maximum Ratings\***

Vcc and input voltages w.r.t. Vss...-0.6V to +7.25V  
 CS1/VPP voltage w.r.t. during programming .....-0.6V to +14V  
 Voltage on A9 w.r.t. Vss .....-0.6V to +13.5V  
 Output voltage w.r.t. Vss .....-0.6V to Vcc+1.0V  
 Temperature under bias .....-65° C to 125° C  
 Storage temperature .....-65° C to 150° C  
 Maximum exposure to UV .....7258Wsec/cm<sup>2</sup>  
 ESD Protection on all pins .....2kV

\*Notice: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

READ OPERATION		DC Characteristics						Vcc = +5V ±10%
								Commercial: Tamb = 0° C to +70° C
								Industrial: Tamb = -40° C to +85° C
Parameter	Part*	Status	Symbol	Min	Max	Units	Conditions	
Input Voltages	all	Logic "1"	V <sub>IH</sub>	2.0	V <sub>CC</sub> +1	V		
			V <sub>IL</sub>	-0.1	0.8	V		
Input Leakage	all		I <sub>LI</sub>	-10	10	µA	V <sub>IN</sub> = 0V to V <sub>CC</sub>	
Output Voltages	all	Logic "1"	V <sub>OH</sub>	2.4		V	I <sub>OH</sub> = -4mA I <sub>OL</sub> = 16mA	
			V <sub>OL</sub>		0.45	V		
Output Leakage	all		I <sub>LO</sub>	-10	10	µA	V <sub>OUT</sub> = 0V to V <sub>CC</sub>	
Input Capacitance	all		C <sub>IN</sub>		6	pF	V <sub>IN</sub> = 0V; Tamb = 25° C; f = 1MHz	
Output Capacitance	all		C <sub>OUT</sub>		12	pF	V <sub>OUT</sub> = 0V; Tamb = 25° C; f = 1MHz	
Power Supply Current, Active	S,L SX,LX	TTL input	I <sub>CC1</sub>		70	mA	V <sub>CC</sub> = 5.5V; f = 2MHz; CS1/VPP = V <sub>L</sub> ; CS2/VFY = CS3/PGM = V <sub>IH</sub> ; I <sub>OUT</sub> = 0mA; V <sub>IL</sub> = -0.1V to 0.8V; V <sub>IH</sub> = 2.0V to V <sub>CC</sub> ; Note 1	
			I <sub>CC2</sub>		80	mA		
Power Supply Current, Standby	S SX		I <sub>CC(S)1</sub>		40	mA		
					45	mA		
Power Supply Current, Standby	L LX L, LX	TTL input	I <sub>CC(S)2</sub>		2	mA	CS1/VPP = V <sub>CC</sub> ±0.2V	
					3	mA		
					100	µA		

\* Parts: S = Standard Power; L = Low Power; X = Industrial Temp Range;  
 Notes: (1) AC Power component above 2 MHz: 4mA/5MHz

**READ OPERATION  
AC Characteristics**

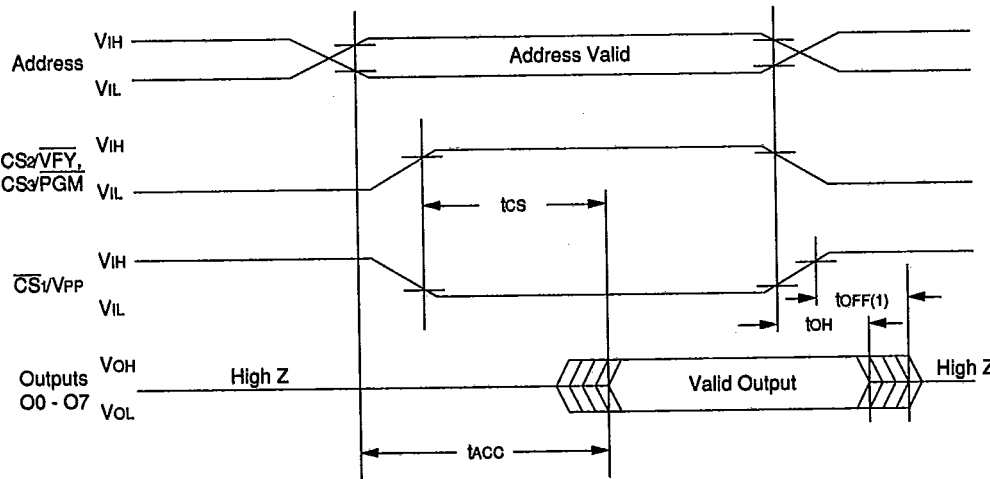
AC Testing Waveform:  $V_{IH} = 3.0V$  and  $V_{IL} = 0.0V$ ;  $V_{OH} = V_{OL} = 1.5V$   
 Output Load: 1 TTL Load +30 pF  
 Input Rise and Fall Times: 5 nsec  
 Ambient Temperature: Commercial:  $T_{amb} = 0^\circ C$  to  $70^\circ C$   
 Industrial:  $T_{amb} = -40^\circ C$  to  $85^\circ C$

Parameter	Part*	Sym	27HC191/ 27HC291-35		27HC191/ 27HC291-40		27HC191/ 27HC291-45		27HC191/ 27HC291-55		Units	Conditions
			Min	Max	Min	Max	Min	Max	Min	Max		
Address to Output Delay	all	tACC		35		40		45		55	ns	
CS to Output Delay	S L	tCS1		25		30		30		40	ns	Note 1
		tCS2		35		40		45		55		
CS to O/P High Impedance	all	tOFF	0	25	0	30	0	30	0	40	ns	Note 2
Output Hold from Address or CS, whichever occurs first	all	tOH	0		0		0		0		ns	

\*Parts: S = Standard Power; L = Low Power  
 Note 1: tCS1, tCS2 to be specified from  $\overline{CS}_1/V_{PP}$ ,  $CS_2/V_{FY}$  and  $CS_3/PGM$ , whichever occurs last  
 Note 2: tOFF is specified from  $\overline{CS}_1/V_{PP}$ ,  $CS_2/V_{FY}$ , or  $CS_3/PGM$  whichever occurs first



**READ WAVEFORMS**



Note: (1) This parameter is sampled and is not 100% tested.

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## PROGRAMMING DC Characteristics

Ambient Temperature:  $T_{amb} = 25^{\circ}C \pm 5^{\circ}C$  **T-46-13-29**  
 For  $\overline{CS}/V_{PP}$  and  $V_{CC}$  Voltages refer to Programming Algorithms

Parameter	Status	Symbol	Min	Max	Units	Conditions
Input Voltages	Logic "1"	$V_{IH}$	2.0	$V_{CC}+1$	V	
	Logic "0"	$V_{IL}$	-0.1	0.8	V	
Input Leakage		$I_{LI}$	-10	10	$\mu A$	$V_{IN} = 0V$ to $V_{CC}$
Output Voltages	Logic "1"	$V_{OH}$	2.4		V	$I_{OH} = -4mA$ $I_{OL} = 16mA$
	Logic "0"	$V_{OL}$		0.45	V	
$V_{CC}$ Current, program & verify		$I_{CC}$		65	mA	
$V_{PP}$ Current, program		$I_{PP}$		30	mA	
A9 Product Identification		$V_H$	11.5	12.5	V	

## PROGRAMMING AC Characteristics

for Program, Program Verify and Program Inhibit Modes

AC Testing Waveform:  $V_{IH} = 2.4V$  and  $V_{IL} = 0.45V$ ;  $V_{OH} = 2.0V$ ;  $V_{OL} = 0.8V$   
 Output Load: 1 TTL Load + 100 pF  
 Ambient Temperature:  $T_{amb} = 25^{\circ}C \pm 5^{\circ}C$   
 For  $\overline{CS}/V_{PP}$  and  $V_{CC}$  Voltages, refer to Programming Algorithms

Parameter	Symbol	Min	Max	Units	Remarks
Address Set-Up Time	$t_{AS}$	2		$\mu s$	
Data Set-Up Time	$t_{DS}$	2		$\mu s$	
Data Hold Time	$t_{DH}$	2		$\mu s$	
Address Hold Time	$t_{AH}$	0		$\mu s$	
Float Delay (3)	$t_{DF}$	0	130	ns	
$V_{CC}$ Set-Up Time	$t_{VCS}$	2		$\mu s$	
Program Pulse Width (1)	$t_{PW}$	0.95	1.05	ms	1 ms typical
Program Pulse Width(1)	$t_{PW}$	95	105	$\mu s$	100 $\mu s$ typical
Data Valid Set-Up Time	$t_{DV}$	2		$\mu s$	
$V_{PP}$ Set-Up Time	$t_{VPS}$	2		$\mu s$	
Overprogram Pulse Width(2)	$t_{OPW}$	2.85	78.75	ms	
Verify Set-up Time	$t_{VFY}$		100	ns	

Notes: (1) For Express algorithm, initial programming width tolerance is 100  $\mu sec \pm 5\%$ . For fast programming algorithm, initial program pulse width tolerance is 1 msec  $\pm 5\%$ .  
 (2) For fast programming algorithm, the length of the overprogram pulse may vary from 2.85 to 78.75 msec as a function of the iteration counter value.  
 (3) This parameter is only sampled and not 100% tested. Output float is defined as the point where data is no longer driven (see timing diagram).



**Read Mode**

For timing and AC characteristics refer to the table Read Waveforms and Read Operation AC characteristics.

The 27HC191/27HC291 memory data is accessed when:

- the chip is selected by setting the  $\overline{CS1}/VPP$  pin low,  $CS2/\overline{VFY}$  high, and  $CS3/\overline{PGM}$  high.

For Read operation on the Low Power version, once the addresses are stable, the address access time ( $t_{ACC}$ ) is equal to the delay from the last CS to be brought active to output ( $t_{CS2}$ ). A faster CS access time ( $t_{CS1}$ ) is available on the standard part to provide the additional time for the decoding of the CS signals.

**Standby Mode**

The standby mode is entered when  $\overline{CS1}/VPP$  is high or when  $CS2/\overline{VFY}$  is low or  $CS3/\overline{PGM}$  is low. When any one of the conditions is met, the supply current will drop from 65mA to 100µA on the low power part and to 35mA on the standard part.

**Programming/Verification**

The 27HC191/27HC291 has to be programmed, and afterward the programmed information verified. The Identity Code can be read to properly set up automatic equipment. Multiple devices in parallel can be programmed using the programming and inhibit modes.

**Programming Algorithm**

Two programming algorithms are available: fast programming and Express.

The fast programming algorithm is the industry standard programming mode that requires both an initial programming pulse and overprogramming pulses. A flow-chart is shown in Figure 1.

The Express algorithm has been developed to improve programming throughput times in a production environment. Up to 10 pulses of 100 µsec each are applied until the byte is verified. No overprogramming is required.

A flow chart of the algorithm is shown in Figure 2.

The programming mode is entered when:

- Vcc is brought to the proper level
- $\overline{CS1}/VPP$  is brought to the proper VH level
- $CS2/\overline{VFY}$  is high
- $CS3/\overline{PGM}$  is pulsed low

Since the erase state is "1" in the array, programming of a "0" is required. The address of the memory location to be programmed is set via pins A0-A10, and the data is presented to pins O0-O7. When data and address are stable, a low going pulse on the  $CS3/\overline{PGM}$  line programs that memory location.

**Verify**

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After the array has been programmed, it must be verified to make sure that all the bits have been correctly programmed. This mode is entered when all the following conditions are met:

- Vcc is at the proper level
- $\overline{CS1}/VPP$  is at the proper VH level
- $CS2/\overline{VFY}$  pin is low
- $CS3/\overline{PGM}$  pin is high

**Inhibit Mode**

When programming multiple devices in parallel with different data only  $CS3/\overline{PGM}$  need to be under separate control to each device. By pulsing the  $CS3/\overline{PGM}$  line low on a particular device, that device will be programmed and all other devices with  $CS3/\overline{PGM}$  held high will not be programmed with data although address and data are available on their input pins.

**Identity Mode**

In this mode specific data is read from the device that identifies the manufacturer as Microchip Technology, and the device type. This mode is entered when pin A9 is taken to VH (11.5 to 12.5 V). The  $\overline{CS1}/VPP$  pin must be at VIL and  $CS2/\overline{VFY}$  and  $CS3/\overline{PGM}$  at VIH. A0 is used to access the two non-erasable bytes whose data appears on O0-O7.

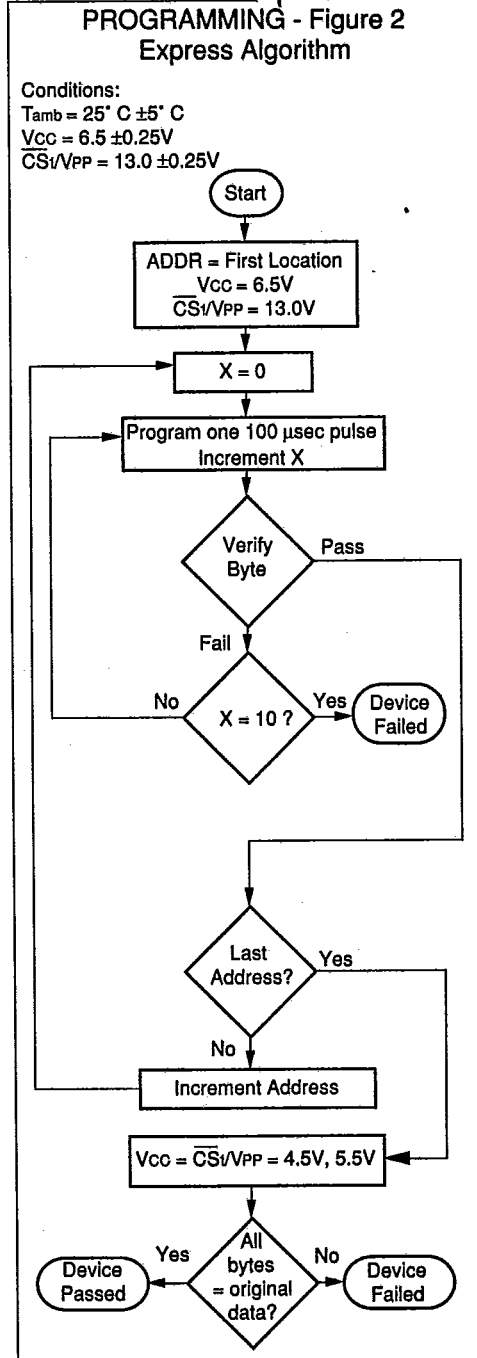
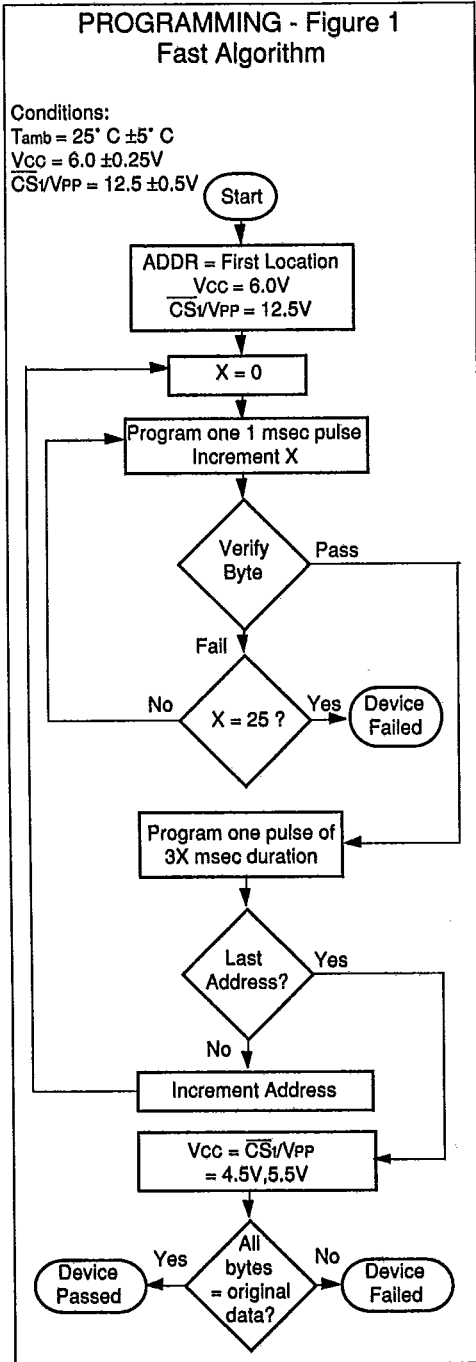
Pin →	Input	Output								
Identity ↓	A0	O7	O6	O5	O4	O3	O2	O1	O0	Hex
Manufacturer	VIL	0	0	1	0	1	0	0	1	29
Device Type	VIH	0	0	0	1	0	1	0	1	15

**Erasure**

Windowed products offer the ability to erase the memory array. The memory matrix is erased to the all "1"s state as a result of being exposed to ultra-violet light at wavelengths  $\leq 4000$  Angstroms (Å). The recommended procedure is to expose the erasure window of device to a commercial shortwave UV source emitting at 2537 Å with an intensity of 12000µW/cm<sup>2</sup> at 1". The erasure time at that distance is about 15 to 20 minutes.

Note: Fluorescent lights and sunlight emit rays at the specified wavelengths. The erasure time is about 3 years or 1 week resp. In these cases. To prevent loss of data, an opaque label should be placed over the erasure window.

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**SALES AND SUPPORT**

To order or to obtain information, e.g., on pricing or delivery, please use the listed part numbers, and refer to the factory or the listed sales offices.

